SQ4917CEY

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Automotive Dual P-Channel 60 V (D-S) 175 °C MOSFET



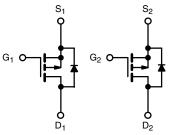
PRODUCT SUMMARY				
V _{DS} (V)	-60			
$R_{DS(on)}$ (Ω) at V_{GS} = -10 V	0.0480			
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.0612			
I _D (A) per leg	-8			
Configuration	Dual			

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



RoHS COMPLIANT HALOGEN FREE



P-Channel MOSFET P-Channel MOSFET

ORDERING INFORMATION

Package	SO-8				
Lead (Pb)-free and halogen-free	SQ4917CEY (for detailed order number please see www.vishay.com/doc?79771)				

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-60	V	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current	T _C = 25 °C	- I _D	-8		
	T _C = 125 °C		-4.75		
Continuous source current (diode conduction)		I _S	-4.5	A	
Pulsed drain current ^a		I _{DM}	-32		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-22.4		
Single pulse avalanche energy		E _{AS}	25	mJ	
Maximum newer dissinction	T _C = 25 °C	D	5	w	
Maximum power dissipation	T _C = 125 °C	P _D	1.67	٧V	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^b	R _{thJA}	110	°C/W	
Junction-to-foot (drain)		R _{thJF}	30	0/10	

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

b. When mounted on 1" square PCB (FR-4 material)

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		•			÷			
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$		-60	-	-		
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = -250 \mu A$		-2.0	-2.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
Zero gate voltage drain current	IDSS	$V_{GS} = 0 V$	V _{DS} = -60 V	-	-	-1		
		V _{GS} = 0 V	V _{DS} = -60 V, T _J = 125 °C	-	-	-50	μA	
		V _{GS} = 0 V	V _{DS} = -60 V, T _J = 175 °C	-	-	-150		
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≤ -5 V	-30	-	-	А	
	D(01)	V _{GS} = -10 V	I _D = -4.3 A	-	0.0421	0.0480		
	_	V _{GS} = -10 V	I _D = -4.3 A, T _J = 125 °C	-	-	0.0780		
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -10 V	-	-	-	0.0960	Ω	
		V _{GS} = -4.5 V	I _D = -3.8 A	-	0.0566	0.0612		
Forward transconductance b	g _{fs}	V _{DS} =	= -15 V, I _D = -4.3 A	-	12	-	S	
Dynamic ^b		I						
Input capacitance	Ciss		V _{DS} = -30 V, f = 1 MHz	-	1575	1910	pF	
Output capacitance	Coss	$V_{GS} = 0 V$		_	175	417		
Reverse transfer capacitance	C _{rss}			-	113	142		
Total gate charge ^c	Qg			-	36.3	65		
Gate-source charge ^c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -30 V, I_D = -5 A$	-	5.3	-	nC	
Gate-drain charge ^c	Q _{gd}			-	8.9	-		
Gate resistance	Rg		f = 1 MHz	1.3	2.36	4	Ω	
Turn-on delay time ^c	t _{d(on)}			_	11	17		
Rise time ^c	tr	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = \text{-30 V}, R_{\text{L}} = 6 \; \Omega \\ I_{\text{D}} \cong \text{-5 A}, V_{\text{GEN}} = \text{-10 V}, R_{\text{g}} = 1 \; \Omega \end{array}$		-	5	17	ns	
Turn-off delay time ^c	t _{d(off)}			-	32	52		
Fall time ^c	t _f			-	5	9		
Source-Drain Diode Ratings and Character	istics b							
Pulsed current ^a	I _{SM}			-	-	-32	А	
Forward voltage	V _{SD}	I _F = -2.8 A, V _{GS} = 0 V		-	-0.79	-1.2	V	
Body diode reverse recovery time	t _{rr}			-	29	58	ns	
Body diode reverse recovery charge	Q _{rr}	I _F = -2.5 A, di/dt = 100 A/μs		-	44	88	nC	
Reverse recovery fall time	t _a			-	24	-	ns	
Reverse recovery rise time	t _b			-	5	-		
Body diode peak reverse recovery current	I _{RM(REC)}			-	-3.4	-	Α	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

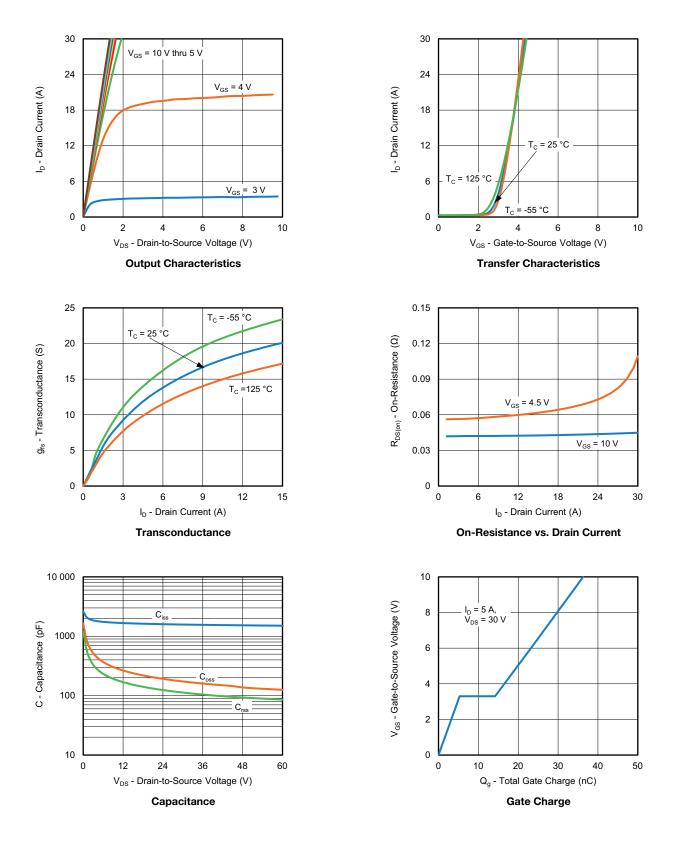
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



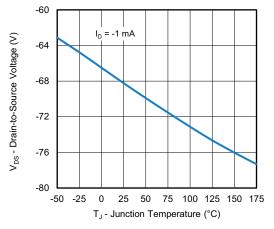
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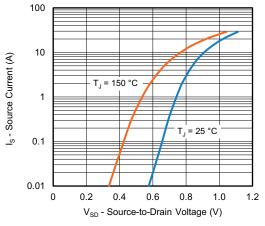


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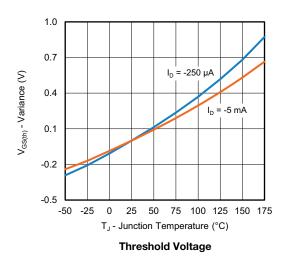
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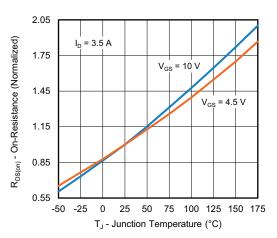


Drain Source Breakdown vs. Junction Temperature

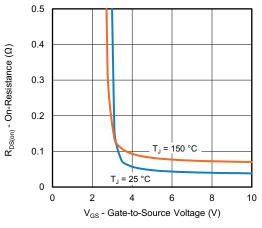


Source Drain Diode Forward Voltage

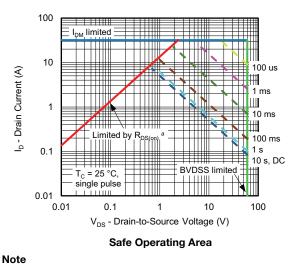




On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



e ∕oc ⊳ min

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

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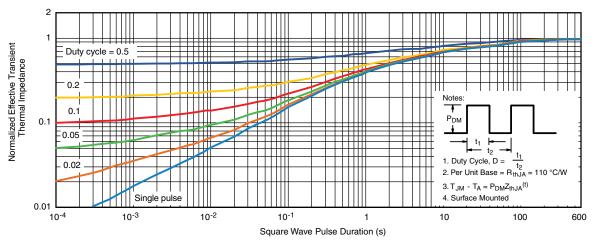
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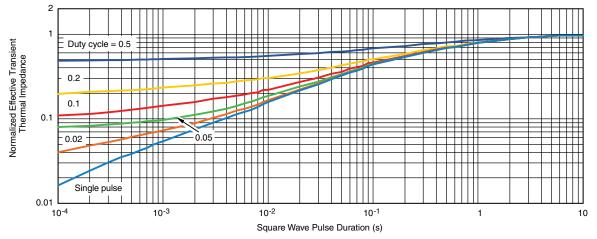


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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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